Preparing an abstract using LaTeX 2$_\epsilon$ for QD2010

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The abstract should occupy a maximum of one A4 page, with margins set to 25mm. All text, equations, figures and references must fit within these margins. This LaTeX file along with the two files qd2010.cls and 2010.clo should be used to generate the abstract. Below is some text set out in this format, together with examples of how to lay out references. Abstracts that do not comply with these instructions may not be considered or may not appear in the abstract book at the conference. When your abstract is complete please submit it as a PDF file ONLY. Details of the IOP paper format for the on-line proceedings can be found at http://www.iop.org/EJ/journal/conf, as well as examples of how to include figures in your abstract. You will need to use the files qd2010.cls and qd2010.clo to compile your abstract. The final paper for contributed talks should be no longer than 4 pages. The page limit for invited talks is 6 pages, and 8 pages for keynote speakers. Delegates will referee the papers at the conference.

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References

[1] Strite S and Morkoc H 1992 *J. Vac. Sci. Technol.* B **10** 1237

[2] Jain S C, Willander M, Narayan J and van Overstraeten R 2000 *J. Appl. Phys*. **87** 965

[3] Nakamura S, Senoh M, Nagahama S, Iwase N, Yamada T, Matsushita T, Kiyoku H and Sugimoto Y 1996 *Japan. J. Appl. Phys.* **35** L74

[4] Akasaki I, Sota S, Sakai H, Tanaka T, Koike M and Amano H 1996 *Electron. Lett.* **32** 1105

[5] O'Leary S K, Foutz B E, Shur M S, Bhapkar U V and Eastman L F 1998 *J. Appl. Phys.* **83** 826

[6] Jenkins D W and Dow J D 1989 *Phys. Rev.* B **39** 3317